

MMBTA05 / MMBTA06

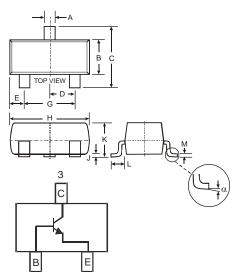
NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMBTA55 / MMBTA56)
- Ideal for Low Power Amplification and Switching
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 3 and 4)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- MMBTA05 Marking (See Page 3): K1G, K1H
- MMBTA06 Marking (See Page 3): K1G
- Ordering & Date Code Information: See Page 3
- Weight: 0.008 grams (approximate)



SOT-23								
Dim	Min	Max						
Α	0.37	0.51						
В	1.20	1.40						
C	2.30	2.50						
D	0.89	1.03						
E	0.45	0.60						
G	1.78	2.05						
Н	2.80	3.00						
J	0.013	0.10						
K	0.903	1.10						
L	0.45	0.61						
М	0.085	0.180						
α	0°	8°						
All Dimensions in mm								

Maximum Ratings @T_A = 25°C unless otherwise specified

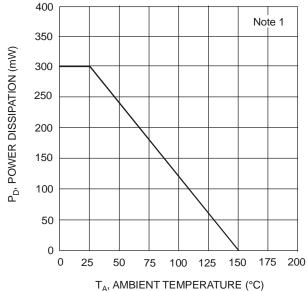
Characteristic	Symbol	MMBTA05	MMBTA06	Unit	
Collector-Base Voltage	V _{CBO}	60	80	V	
Collector-Emitter Voltage	V _{CEO}	60	80	V	
Emitter-Base Voltage	V _{EBO}	4	.0	V	
Collector Current - Continuous (Note 1)	Ic	5	00	mA	
Power Dissipation (Note 1)	P _D	3	00	mW	
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	4	17	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to	+150	°C	

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol Min		Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 2)	•		•	•	•	•	
Collector-Base Breakdown Voltage	MMBTA05 MMBTA06	V _{(BR)CBO}	60 80	_	V	$I_C = 100 \mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage	MMBTA05 MMBTA06	$V_{(BR)CEO}$	60 80	_	V	$I_C = 1.0 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage		$V_{(BR)EBO}$	4.0	_	V	$I_E = 100 \mu A, I_C = 0$	
Collector Cutoff Current	MMBTA05 MMBTA06	I _{CBO}	_	100	nA	$V_{CB} = 60V, I_{E} = 0$ $V_{CB} = 80V, I_{E} = 0$	
Collector Cutoff Current	MMBTA05 MMBTA06	I _{CES}	_	100	nA	$V_{CE} = 60V, I_{BO} = 0V$ $V_{CE} = 80V, I_{BO} = 0V$	
ON CHARACTERISTICS (Note 2)			_				
DC Current Gain		h _{FE}	100	_	_	$I_C = 10 \text{mA}, V_{CE} = 1.0 \text{V}$ $I_C = 100 \text{mA}, V_{CE} = 1.0 \text{V}$	
Collector-Emitter Saturation Voltage		$V_{CE(SAT)}$	_	0.25	V	$I_C = 100 \text{mA}, I_B = 10 \text{mA}$	
Base-Emitter Saturation Voltage		V _{BE(SAT)}	_	1.2	V	$I_C = 100 \text{mA}, V_{CE} = 1.0 \text{V}$	
SMALL SIGNAL CHARACTERISTICS							
Current Gain-Bandwidth Product		f⊤	100	_	MHz	$V_{CE} = 2.0V, I_{C} = 10mA,$ f = 100MHz	

- Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
 - 2. Short duration pulse test used to minimize self-heating effect.
 - 3. No purposefully added lead. Halogen and Antimony Free.
 - 4. Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.





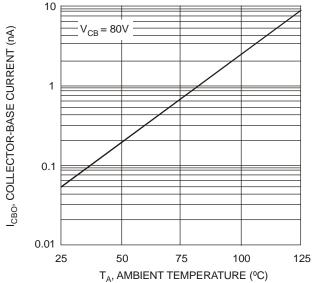
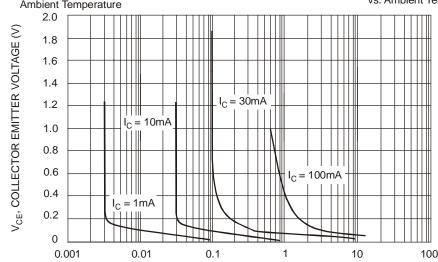


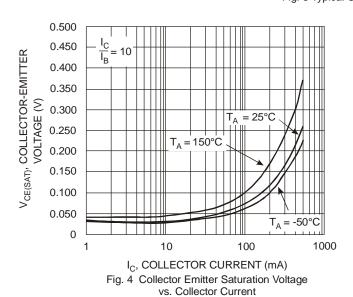
Fig. 1, Max Power Dissipation vs
Ambient Temperature

Fig. 2 Typical Collector-Cutoff Current vs. Ambient Temperature



I_{B,} BASE CURRENT (mA) Fig. 3 Typical Collector Saturation Region

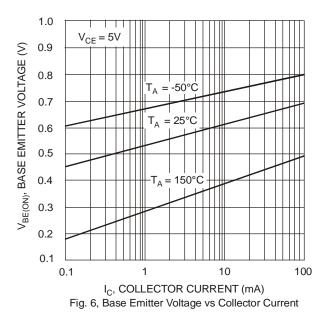
10,000

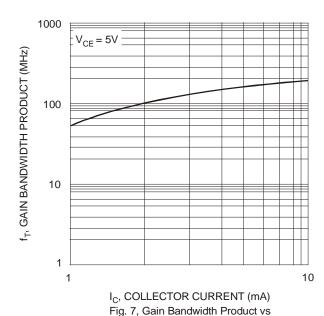


1,000 T_A = 150°C T_A = 25°C T_A = 25°C

I_C, COLLECTOR CURRENT (mA) Fig. 5, DC Current Gain vs Collector Current







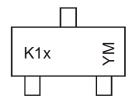
Collector Current

Ordering Information (Note 5)

Device	Packaging	Shipping
MMBTA05-7-F	SOT-23	3000/Tape & Reel
MMBTA06-7-F	SOT-23	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K1x = Product Type Marking Code, e.g. K1G

YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

														_	
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	Ш	М	N	Р	R	S	Т	U	V	W	Х	Υ	Z
Month	Jan	Fe	b	Mar	Apr	May	Ju	ın	Jul	Aug	Sep	Oc	t	Nov	Dec

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